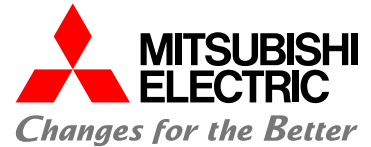


PRESS CONFERENCE



Tuesday, 9th of May 2023

PCIM Europe, Messezentrum 1
90471 Nuremberg (Germany)
NCC Ost, Ebene 3, Room Shanghai

Press Kit /
Personal Profile

PERSONAL PROFILE DR. MASAYOSHI TAKEMI

Executive Officer, Group President
Semiconductor & Device Group
Mitsubishi Electric Corporation, Japan



Age

57 Years

Education

1999 Doctor of Philosophy in Engineering
1991 Graduated Kyoto University (Japan)
Master's Degree
Graduate School of Engineering

Professional Experience

Apr. 2022 Executive Officer, Group President, Semiconductor & Device
Apr. 2021 Corporate Executive, Group Vice President, Senior General Manager, High Frequency & Optical Device Works
Apr. 2019 Group Vice President, Senior General Manager, High Frequency & Optical Device Works
Apr. 2018 Deputy Senior General Manager, High Frequency & Optical Device Works
General Manager, Quality Assurance Dept., High Frequency & Optical Device Works
Apr. 2016 Deputy Senior General Manager, Planning & Administration Dept.
Apr. 2014 General Manager, Optical Device Dept., High Frequency & Optical Device Works
Oct. 2010 General Manager, Wafer Manufacturing Dept., High Frequency & Optical Device Works
Jan. 2010 Deputy General Manager, Wafer Manufacturing Dept., High Frequency & Optical Device Works
Apr. 1991 Joined Mitsubishi Electric Corporation